TOSHIBA Transistor Silicon NPN Epitaxial Planar Type

# 2SC5108FT

## For VCO Application

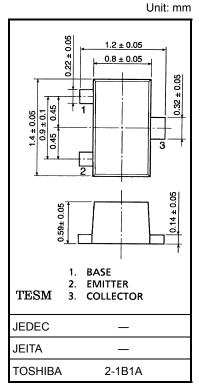
## Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	V <sub>CBO</sub>	20	V
Collector-emitter voltage	V <sub>CEO</sub>	10	V
Emitter-base voltage	V <sub>EBO</sub>	3	V
Base current	I <sub>B</sub>	15	mA
Collector current	Ic	30	mA
Collector power dissipation	PC	100	mW
Junction temperature	Tj	125	°C
Storage temperature range	T <sub>stg</sub>	<i>–</i> 55∼125	°C

Note:

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).



Weight: 0.0022 g (typ.)

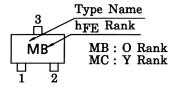
## **Electrical Characteristics (Ta = 25°C)**

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I <sub>CBO</sub>	$V_{CB} = 10 \text{ V}, I_{E} = 0$	_	_	0.1	μА
Emitter cut-off current	I <sub>EBO</sub>	$V_{EB} = 1 \text{ V, } I_C = 0$	_	_	0.1	μА
DC current gain	h <sub>FE</sub> (Note 1)	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 5 mA	80	_	240	
Transition frequency	f <sub>T</sub>	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 5 mA	4	6	_	GHz
Insertion gain	S <sub>21e</sub>   <sup>2</sup>	$V_{CE} = 5 \text{ V}, I_{C} = 5 \text{ mA}, f = 1 \text{ GHz}$	7	11	_	dB
Output capacitance	C <sub>ob</sub>	V <sub>CR</sub> = 5 V, I <sub>F</sub> = 0, f = 1 MHz (Note 2)	_	0.7	_	pF
Reverse transfer capacitance	C <sub>re</sub>	VCB = 5  V, IE = 0, I = 1  IVID2 (Note 2)	_	0.5	0.9	pF
Collector-base time constant	C <sub>c</sub> ·r <sub>bb</sub> '	$V_{CB} = 5 \text{ V}, I_{C} = 3 \text{ mA}, f = 30 \text{ MHz}$	_	5.5	10	ps

Note 1: hFE classification O: 80~160, Y: 120~240

Note 2: Cre is measured by 3 terminal method with capacitance bridge.

#### Marking



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#### **RESTRICTIONS ON PRODUCT USE**

20070701-EN GENERAL

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